

NPN General Purpose Amplifier

SUPERSOT™-6 Surface Mount Package

FMB5551

- This device is designed for general purpose high voltage amplifiers and gas discharge display driving
- Sourced from process 16
- See MMBT5551 for characteristics
- Pb-Free, Halogen Free/BFR Free and RoHS Compliant

ABSOLUTE MAXIMUM RATINGS

 $(T_A = 25^{\circ}C \text{ unless otherwise noted.})$

Symbol	Parameter	Value	Unit	
V _{CEO}	Collector-Emitter Voltage	160	٧	
V _{CBO}	Collector-Base Voltage	180	٧	
V _{EBO}	Emitter-Base Voltage	6	V	
I _C	Collector Current (DC)	600	mA	
P _C	Collector Dissipation (T _A = 25°C) (Note 1)	0.7	W	
T _J	Junction Temperature	150	°C	
T _{STG}	Storage Temperature Range	-55 to +150	°C	
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	180	°C/W	

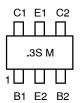
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. PD total, for both transistors. For each transistor, PD = 350 mW.



TSOT23 6-Lead CASE 419AG

MARKING DIAGRAM



.3S = Specific Device Code

M = Date Code

ORDERING INFORMATION

Device	Package	Shipping [†]		
FMB5551	TSOT23 6-Lead (Pb-Free)	3,000 / Tape & Reel		

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

FMB5551

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted.)

Symbol	Parameter	Test Conditions	Min	Тур	Max	Unit
OFF CHAF	ACTERISTICS			•		•
BV _{CEO}	Collector-Emitter Voltage	I _C = 1 mA	160	_	_	V
BV _{CBO}	Collector-Base Voltage	I _C = 10 μA	180	-	-	V
BV _{EBO}	Emitter-Base Voltage	I _E = 10 μA	6	-	-	V
I _{CBO}	Collector Cut-off Current	V _{CB} = 120 V V _{CB} = 120 V, T = 100°C	- -	- -	50 50	nA μA
I _{EBO}	Emitter Cut-off Current	V _{EB} = 4 V	-	-	50	nA
ON CHAR	ACTERISTICS					
h _{FE}	DC Current Gain	$V_{CE} = 5 \text{ V, } I_{C} = 1 \text{ mA}$ $V_{CE} = 5 \text{ V, } I_{C} = 10 \text{ mA}$ $V_{CE} = 5 \text{ V, } I_{C} = 50 \text{ mA}$	80 80 30	- - -	- 250 -	
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C = 10 mA, I _B = 1 mA I _C = 50 mA, I _B = 5 mA	- -	- -	0.15 0.2	V
V _{BE} (sat)	Base-Emitter Saturation Voltage	$I_C = 10 \text{ mA}, I_B = 1 \text{ mA}$ $I_C = 50 \text{ mA}, I_B = 5 \text{ mA}$	- -	- -	1 1	V
SMALL SIG	GNAL CHARACTERISTICS					
C _{ob}	Output Capacitance	V _{CB} = 10 V, f = 1 MHz	-	-	6	pF
C _{ib}	Input Capacitance	V _{CB} = 0.5 V, f = 1 MHz	-	-	20	pF
f _T	Current gain Bandwidth Product	V _{CE} = 10 V, I _C = 10 mA, f = 100 MHz	100	-	300	MHz
NF	Noise Figure	V_{CE} = 5 V, I_{C} = 200 μA, f = 1 MHz, R_{S} = 2 kΩ, B = 200 Hz	ı	-	8	dB
h _{FE}	Small Signal Current Gain	V _{CE} = 10 V, I _C = 1 mA, f = 1 kHz	50	_	250	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

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